

Data sheet acquired from Harris Semiconductor SCHS155C

CD54HC164, CD74HC164, CD54HCT164

High-Speed CMOS Logic 8-Bit Serial-In/Parallel-Out Shift Register

October 1997 - Revised August 2003

Features

- · Buffered Inputs
- Asynchronous Master Reset
- Typical $f_{MAX} = 60MHz$ at $V_{CC} = 5V$, $C_L = 15pF$, $T_{\Delta} = 25^{\circ}C$
- Fanout (Over Temperature Range)
- Wide Operating Temperature Range ... -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility, V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, $I_I \le 1\mu A$ at V_{OL} , V_{OH}

Description

The 'HC164 and 'HCT164 are 8-bit serial-in parallel-out shift registers with asynchronous reset. Data is shifted on the positive edge of Clock (CP). A LOW on the Master Reset (\overline{MR}) pin resets the shift register and all outputs go to the LOW state regardless of the input conditions. Two Serial Data inputs (DS1 and DS2) are provided, either one can be used as a Data Enable control.

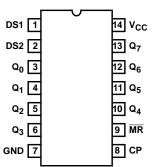
Ordering Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE
CD54HC164F3A	-55 to 125	14 Ld CERDIP
CD54HCT164F3A	-55 to 125	14 Ld CERDIP
CD74HC164E	-55 to 125	14 Ld PDIP
CD74HC164M	-55 to 125	14 Ld SOIC
CD74HC164MT	-55 to 125	14 Ld SOIC
CD74HC164M96	-55 to 125	14 Ld SOIC
CD74HCT164E	-55 to 125	14 Ld PDIP
CD74HCT164M	-55 to 125	14 Ld SOIC
CD74HCT164MT	-55 to 125	14 Ld SOIC
CD74HCT164M96	-55 to 125	14 Ld SOIC

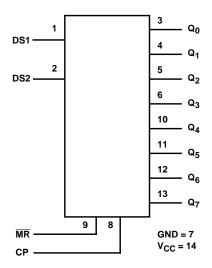
NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel. The suffix T denotes a small-quantity reel of 250.

Pinout

CD54HC164, CD54HCT164 (CERDIP) CD74HC164, CD74HCT164 (PDIP, SOIC) TOP VIEW



Functional Diagram



TRUTH TABLE

		INP	UTS		OUTPUTS			
OPERATING MODE	MR	СР	DS1	DS2	Q ₀	Q ₁ - Q ₇		
RESET (CLEAR)	L	Х	х	Х	L	L-L		
Shift	Н	↑	1	I	L	90 - 96		
	Н	1	1	h	L	90 - 96		
	Н	1	h	I	L	90 - 96		
	Н	1	h	h	Н	90 - 96		

H= High Voltage Level.

h= High Voltage Level One Set-up Time Prior To The Low-to-high Clock Transition.

I= Low Voltage Level One Set-up Time Prior To The Low-to-high Clock Transition.

L= Low Voltage Level.

X= Don't Care.

 \uparrow = Transition from Low to High Level.

 $\ensuremath{q_{\text{n}}}\xspace=$ Lower Case Letters Indicate The State Of the Reference Input Clock Transition.

Absolute Maximum Ratings

DC Supply Voltage, V_{CC} -0.5V to 7V DC Input Diode Current, I_{IK} DC Output Diode Current, I_{OK} DC Output Source or Sink Current per Output Pin, IO For $V_O > -0.5V$ or $V_O < V_{CC} + 0.5V$±25mA

Thermal Information

Thermal Resistance (Typical, Note 1)	θ_{JA} (oC/W)
E (PDIP) Package	80
M (SOIC) Package	86
Maximum Junction Temperature	150 ^o C
Maximum Storage Temperature Range	65°C to 150°C
Maximum Lead Temperature (Soldering 10s)	300°C
(SOIC - Lead Tips Only)	

Operating Conditions

Temperature Range (T _A)55°C to 125°C
Supply Voltage Range, V _{CC}
HC Types2V to 6V
HCT Types
DC Input or Output Voltage, V _I , V _O 0V to V _{CC}
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

			ST ITIONS		25°C			-40°C T	O 85°C	-55°C TO 125°C		
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES												
High Level Input VIH	V _{IH}	-	-	2	1.5	ı	-	1.5	-	1.5	-	V
Voltage				4.5	3.15	1	-	3.15	-	3.15	-	V
				6	4.2	ı	-	4.2	-	4.2	-	V
Low Level Input	V _{IL}	-	-	2	ı	ı	0.5	-	0.5	-	0.5	V
Voltage				4.5	ı	ı	1.35	-	1.35	-	1.35	٧
				6	ı	i	1.8	-	1.8	-	1.8	V
High Level Output V _{OH} Voltage CMOS Loads	V _{OH}	V _{IH} or	-0.02	2	1.9	-	-	1.9	-	1.9	-	٧
		V _{IL}	-0.02	4.5	4.4	i	-	4.4	-	4.4	-	٧
			-0.02	6	5.9	ı	-	5.9	-	5.9	-	V
High Level Output			-4	4.5	3.98	-	-	3.84	-	3.7	-	٧
Voltage TTL Loads			-5.2	6	5.48	-	-	5.34	-	5.2	-	٧
Low Level Output	V _{OL}	V _{IH} or	0.02	2	-	-	0.1	-	0.1	-	0.1	٧
Voltage CMOS Loads		V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	٧
			0.02	6	-	-	0.1	-	0.1	-	0.1	٧
Low Level Output			4	4.5	-	-	0.26	-	0.33	-	0.4	٧
Voltage TTL Loads			5.2	6	-	-	0.26	-	0.33	-	0.4	٧
Input Leakage Current	II	V _{CC} or GND	-	6	ı	-	±0.1	-	±1	-	±1	μА
Quiescent Device Current	lcc	V _{CC} or GND	0	6	ı	-	8	-	80	-	160	μА

DC Electrical Specifications (Continued)

			ST ITIONS			25°C		-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HCT TYPES												
High Level Input Voltage	V _{IH}	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V _{OH}	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lı	V _{CC} to GND	0	5.5	-	-	±0.1	-	±1	-	±1	μА
Quiescent Device Current	Icc	V _{CC} or GND	0	5.5	-	-	8	-	80	-	160	μΑ
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI _{CC} (Note 2)	V _{CC} -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μА

NOTE:

2. For dual-supply systems theoretical worst case (V_I = 2.4V, V_{CC} = 5.5V) specification is 1.8mA.

HCT Input Loading Table

INPUT	UNIT LOADS
Date Shift-In (1, 2)	0.3
MR	0.9
Clock	0.7

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Specifications table, e.g. 360 μ A max at 25 $^{\circ}$ C.

Prerequisite For Switching Function

			25°C		-40°C T	O 85°C	-55°C TO 125°C		
PARAMETER	SYMBOL	V _{CC} (V)	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES				-		-	-	_	-
Maximum Clock Frequency	f _{MAX}	2	6	-	5	-	4	-	MHz
		4.5	30	-	24	-	20	-	MHz
		6	35	-	28	-	24	-	MHz
MR Pulse Width	t _w	2	60	-	75	-	90	-	ns
		4.5	12	-	15	-	18	-	ns
		6	10	-	13	-	15	-	ns

Prerequisite For Switching Function (Continued)

			25	°C	-40°C T	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	V _{CC} (V)	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
CP Pulse Width	t _W	2	80	-	100	-	120	-	ns
		4.5	16	-	20	-	24	-	ns
		6	14	-	17	-	20	-	ns
Set-up Time	t _{SU}	2	60	-	75	-	90	-	ns
		4.5	12	-	15	-	18	-	ns
		6	10	-	13	-	15	-	ns
Hold Time	t _H	2	4	-	4	-	4	-	ns
		4.5	4	-	4	-	4	-	ns
		6	4	-	4	-	4	-	ns
MR to Clock,	t _{REM}	2	80	-	100	-	120	-	ns
Removal Time		4.5	16	-	20	-	24	-	ns
		6	14	-	17	-	20	-	ns
HCT TYPES	•	•	•	•	•		•	•	•
Maximum Clock Frequency	f _{MAX}	4.5	27	-	22	-	18	-	MHz
MR Pulse Width	t _w	6	18	-	23	-	27	-	ns
CP Pulse Width	t _w	4.5	18	-	23	-	27	-	ns
Set-up Time	t _{SU}	6	12	-	15	-	18	-	ns
Hold Time	t _H	4.5	4	-	4	-	4	-	ns
MR to Clock, Removal Time	t _{REM}	6	16	-	20	-	24	-	ns

Switching Specifications Input t_r , $t_f = 6ns$

		TEST		25	o _C	-40°C TO 85°C	-55°C TO 125°C	
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	TYP	MAX	MAX	MAX	UNITS
HC TYPES								
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	170	212	255	ns
CP to Q _n			4.5	-	34	43	51	ns
		C _L = 15pF	5	14	-	-	-	ns
		C _L = 50pF	6	-	29	36	43	ns
MR to Q _n	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	140	175	210	ns
			4.5	-	28	35	42	ns
		C _L = 15pF	5	11	-	-	-	ns
		C _L = 50pF	6	-	24	30	36	ns
Output Transition Times	t _{TLH} , t _{THL}	C _L = 50pF	2	-	75	-	110	ns
			4.5	-	15	-	22	ns
			6	-	13	-	19	ns
Maximum Clock Frequency	f _{MAX}	C _L = 15pF	5	60	-	-	-	MHz
Input Capacitance	C _{IN}	-	-	ı	10	10	10	pF

Switching Specifications Input t_r, t_f = 6ns (Continued)

		TEST		25	°C	-40°C TO 85°C	-55°C TO 125°C				
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	TYP	MAX	MAX	MAX	UNITS			
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	-	5	47	-	-	-	pF			
HCT TYPES											
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	36	45	54	ns			
CP to Q _n		C _L = 15pF	5	15	-	-	-	ns			
MR to Q _n	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	38	46	57	ns			
		C _L = 15pF	5	16	-	=	-	ns			
Output Transition Times	t _{TLH} , t _{THL}	C _L = 50pF	4.5	-	15	19	22	ns			
Input Capacitance	C _{IN}	-	-	-	-	=	-	pF			
Maximum Clock Frequency	f _{MAX}	C _L = 15pF	-	54	-	=	-	MHz			
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	-	5	49	10	10	10	pF			

NOTES:

- 3. $C_{\mbox{\scriptsize PD}}$ is used to determine the dynamic power consumption, per device.
- 4. $P_D = V_{CC}^2 f_i + \sum (C_L V_{CC}^2 + f_O)$ where f_i = Input Frequency, f_O = Output Frequency, C_L = Output Load Capacitance, V_{CC} = Supply Voltage.

Test Circuits and Waveforms

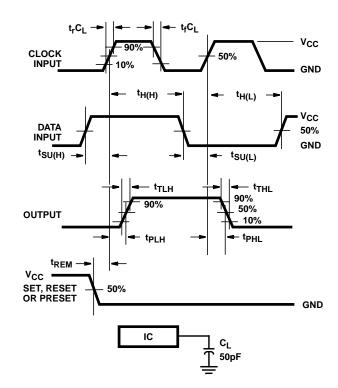


FIGURE 1. HC SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS

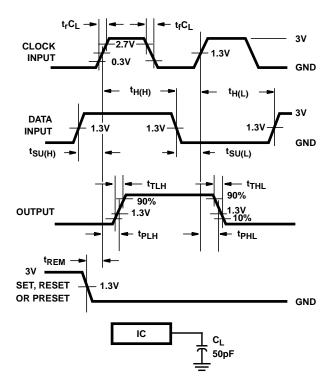


FIGURE 2. HCT SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS





i.com 6-Jun-2005

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finisl	n MSL Peak Temp ⁽³⁾
5962-8970401CA	ACTIVE	CDIP	J	14	1	TBD	Call TI	Level-NC-NC-NC
CD54HC164F	ACTIVE	CDIP	J	14	1	TBD	Call TI	Level-NC-NC-NC
CD54HC164F3A	ACTIVE	CDIP	J	14	1	TBD	Call TI	Level-NC-NC-NC
CD54HCT164F3A	ACTIVE	CDIP	J	14	1	TBD	Call TI	Level-NC-NC-NC
CD74HC164E	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD74HC164EE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD74HC164M	ACTIVE	SOIC	D	14	50	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD74HC164M96	ACTIVE	SOIC	D	14	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD74HC164M96E4	ACTIVE	SOIC	D	14	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD74HC164ME4	ACTIVE	SOIC	D	14	50	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD74HC164MT	ACTIVE	SOIC	D	14	250	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD74HC164MTE4	ACTIVE	SOIC	D	14	250	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD74HCT164E	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD74HCT164M	ACTIVE	SOIC	D	14	50	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD74HCT164M96	ACTIVE	SOIC	D	14	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD74HCT164M96E4	ACTIVE	SOIC	D	14	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD74HCT164ME4	ACTIVE	SOIC	D	14	50	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD74HCT164MT	ACTIVE	SOIC	D	14	250	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD74HCT164MTE4	ACTIVE	SOIC	D	14	250	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



PACKAGE OPTION ADDENDUM

6-Jun-2005

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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14 LEADS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDSO-G14)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-012 variation AB.



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